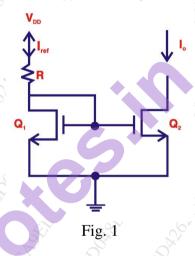
Time: 3 Hours Max. Marks: 80

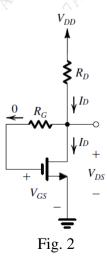
Q1 is compulsory. Attempt any three from Q2 to Q6.

Q1	Solve any Four 5 marks each
A	Explain the operation of a semiconductor pn junction diode with the help
	VI characteristics.
В	Explain Miller's capacitance theorem.
C	Compare BJT CE amplifier and JFET CS amplifier.
D	What is crossover distortion in Class B power amplifiers?
Е	Let $V_{DD} = 5V$, $V_{t,1} = 1V$, $k_{n,1}' = 20\mu A/V^2$ and $R = 1K\Omega$. What should be
	$(W/L)_1$ needed for creating $I_{ref} = 1 \text{mA}$? What should be $(W/L)_2$ if
	$I_0 = 7 \text{mA}$? Refer Fig. 1



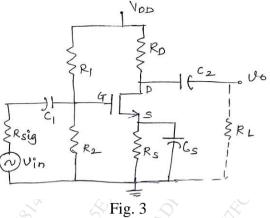
O2 10 marks each

Design a feedback bias circuit for n-channel E-MOSFET with operating drain current of 0.5 mA. Given: $V_{DD} = 5 \text{ V}$, $k'_n = 100 \mu\text{A/V}^2$, $W = 1.8 \mu\text{m}$, L = 180 nm, $V_{T0n} = 1 \text{ V}$, Use a standard resistor value for R_D and recalculate I_D and V_D . Refer fig. 2.

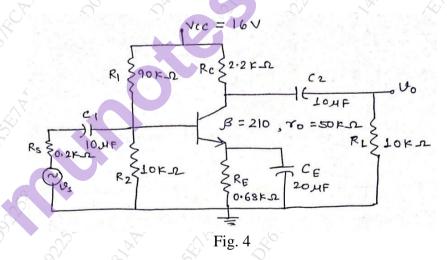


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B Draw a small signal equivalent circuit of an E-MOSFET CS amplifier given in fig. 3 and derive the expression for voltage gain, input resistance and output resistance.



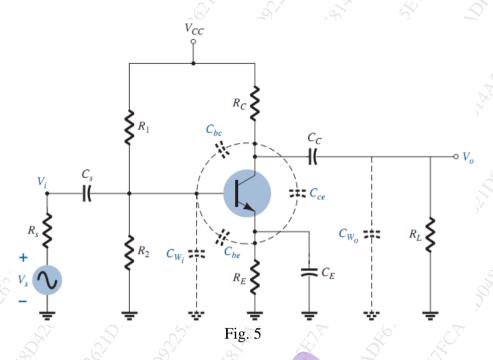
A Explain construction and working of n-channel E-MOSFET 5 marks
B What is thermal runaway and how it can be avoided? 5 marks
C Calculate low cutoff frequencies due to coupling and bypass capacitors of the circuit given in fig. 4 10 marks



Q4

Determine f_{β} and f_T for the given circuit. Assume $I_E = 1.65$ mA. Refer Fig. 5 marks

$$\begin{split} R_s &= 1 \text{ k}\Omega, R_1 = 40 \text{ k}\Omega, R_2 = 10 \text{ k}\Omega, R_E = 2 \text{ k}\Omega, R_C = 4 \text{ k}\Omega, R_L = 2.2 \text{ k}\Omega \\ C_s &= 10 \text{ }\mu\text{F}, C_C = 1 \text{ }\mu\text{F}, C_E = 20 \text{ }\mu\text{F} \\ h_{fe} &= 100, r_o = \infty \text{ }\Omega, V_{CC} = 20 \text{ V} \\ C_\pi(C_{be}) &= 36 \text{ pF}, C_u(C_{bc}) = 4 \text{ pF}, C_{ce} = 1 \text{ pF}, C_{W_i} = 6 \text{ pF}, C_{W_o} = 8 \text{ pF} \end{split}$$



B Draw and explain high frequency model for BJT in CE configuration.

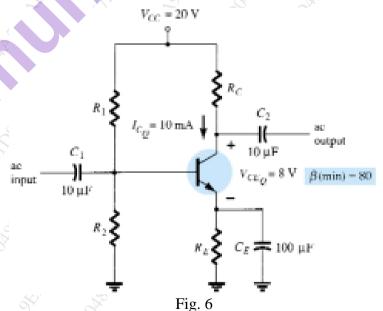
5 marks

C Draw and explain a series fed class A power amplifier with the help of neat diagram and waveforms and derive the expression of power efficiency.

10 Marks

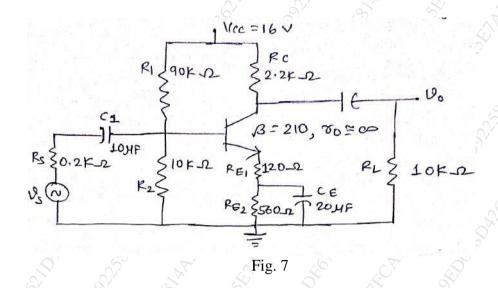
Q5

Design a voltage divider bias circuit to operate at the given conditions. Calculate the stability factors S(Ico), S(VBE), $S(\beta)$. Refer Fig. 6 **10 Marks**



Determine the input impedance, output impedance, voltage gain and current gain for the given circuit. Refer fig. 7 10 Marks

P.



Q6

- A Derive the equation of CMRR for the MOS differential pair amplifier. 10 Marks
- B Write short note on:
 - i) E-MOSFET as a differential amplifier

5 Marks

ii) Zener diode as a voltage regulator

5 Marks

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